

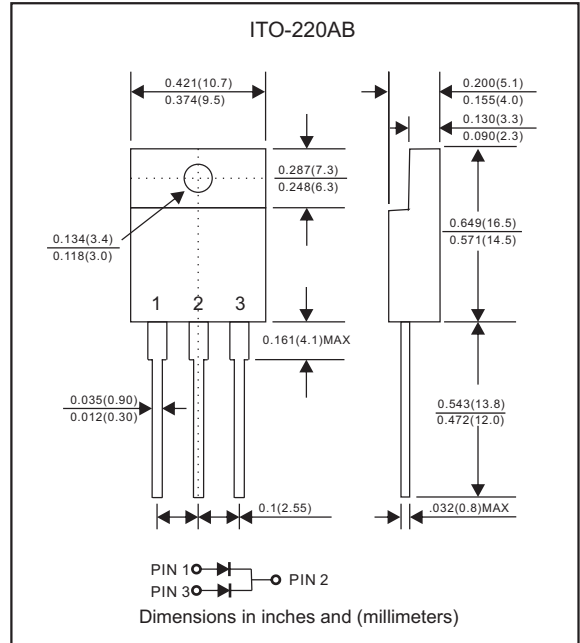
### Features

- Extremely LOW VF
- Trench MOS schottky technology
- Low power loss/high efficiency
- High frequency operation
- High forward surge capability
- Suffix "-H" indicates Halogen-free parts,ex.MBR40U150FCT-H

### Mechanical data

- Epoxy:UL 94-V0 rated flame retardant
- Case:JEDEC ITO-220AB molded plastic body over passivated chip
- Lead :Axialleads,solderable per MIL-STD -202, Method 208 guaranteed
- Polarity :Color band denotes cathode end
- Mounting Position :Any

### Package outline



### Maximum ratings and Electrical Characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	See Fig.1	$I_o$			40.0	A
Forward surge current	8.3ms single half sine-wave (JEDEC methode)	$I_{FSM}$			250	A
Reverse current	$V_R = V_{RRM} T_J = 25^\circ\text{C}$	$I_R$			0.1	mA
	$V_R = V_{RRM} T_J = 125^\circ\text{C}$				20	
Thermal resistance	Junction to case (1)	$R_{\theta JC}$		4		$^\circ\text{C/W}$
Storage temperature		$T_{STG}$	-55		+150	$^\circ\text{C}$

NOTE : (1) Device mounted on additional heatsink, (50mm x 50mm x 23mm Al heatsink).

SYMBOLS	$V_{RRM}^{*1}$ (V)	$V_{RMS}^{*2}$ (V)	$V_R^{*3}$ (V)	$V_F^{*4}$ (V)	Operating temperature $T_J$ , ( $^\circ\text{C}$ )
MBR40U150FCT	150	105	150	0.85	-55 to +150

\*1 Repetitive peak reverse voltage

\*2 RMS voltage

\*3 Continuous reverse voltage

\*4 Maximum forward voltage

$I_F = 20.0\text{A}$

## Rating and characteristic curves

FIG. 1- DERATING CURVE OUTPUT RECTIFIED CURRENT

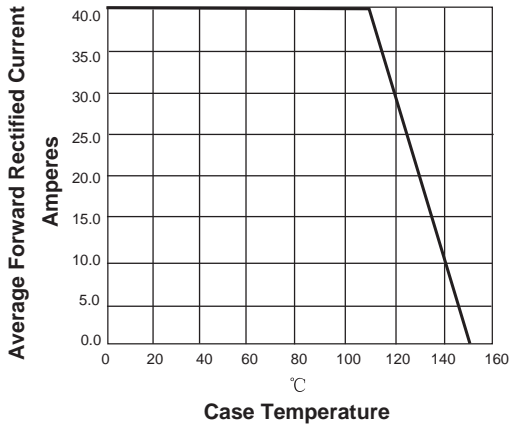


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT PER LEG

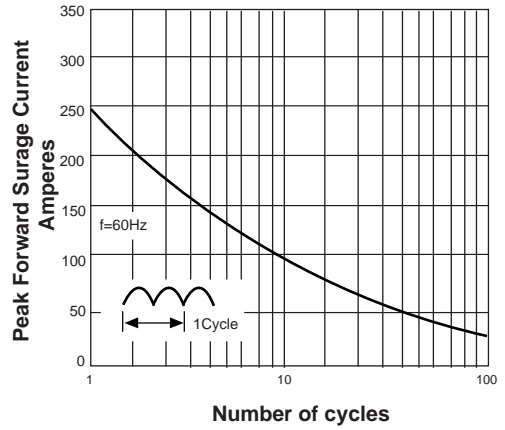


FIG. 3-TYPICAL FORWARD VOLTAGE CHARACTERISTICS

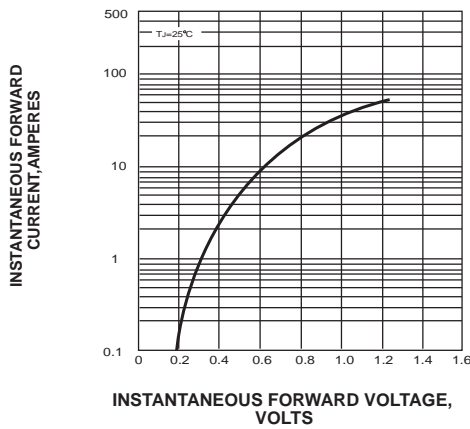
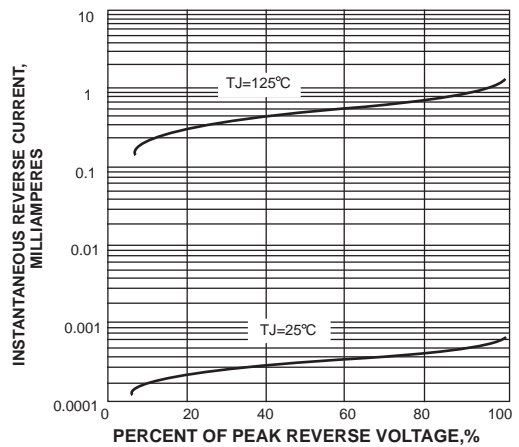
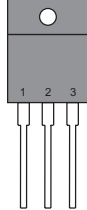
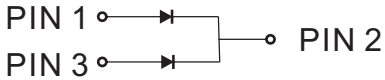


FIG. 4-TYPICAL REVERSE LEAKAGE CHARACTERISTICS



### Pinning information

Pin	Simplified outline	Symbol
Pin1 anode Pin2 cathode Pin3 anode		

### Marking

Type number	Marking code
MBR40U150FCT	MBR40U150FCT